

FEATURES

High Speed

250 MHz -3 dB Bandwidth ($G = +1$)

3000 V/ μ s Slew Rate

21 ns Settling Time to 0.1%

1.8 ns Rise Time for 2 V Step

Low Power

3.5 mA/Amp Power Supply Current (35 mW/Amp)

Single Supply Operation

Fully Specified for +5 V Supply

Good Video Specifications ($R_L = 150 \Omega$, $G = +2$)

Gain Flatness 0.1 dB to 30 MHz

0.04% Differential Gain Error

0.10° Differential Phase Error

Low Distortion

-78 dBc THD at 5 MHz

-61 dBc THD at 20 MHz

High Output Current of 50 mA

Available in a 14-Lead SOIC

APPLICATIONS

Image Scanners

Active Filters

Video Switchers

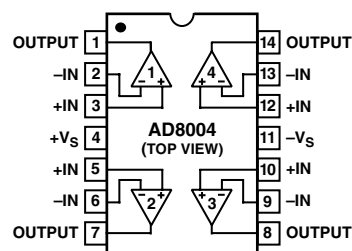
Special Effects

GENERAL DESCRIPTION

The AD8004 is a quad, low power, high speed amplifier designed to operate on single or dual supplies. It utilizes a current feedback architecture and features high slew rate of 3000 V/ μ s making the AD8004 ideal for handling large amplitude pulses. Additionally, the AD8004 provides gain flatness of 0.1 dB to

CONNECTION DIAGRAM

SOIC (R) Package



30 MHz while offering differential gain and phase error of 0.04% and 0.10°. This makes the AD8004 suitable for video electronics such as cameras and video switchers.

The AD8004 offers low power of 3.5 mA/amplifier and can run on a single +4 V to +12 V power supply, while being capable of delivering up to 50 mA of load current. All this is offered in a small 14-lead SOIC package. These features make this amplifier ideal for portable and battery powered applications where size and power are critical.

The outstanding bandwidth of 250 MHz along with 3000 V/ μ s of slew rate make the AD8004 useful in many general-purpose, high speed applications where dual power supplies of up to ± 6 V and single supplies from 4 V to 12 V are needed. The AD8004 is available in the industrial temperature range of -40°C to $+85^\circ\text{C}$ in the R package.

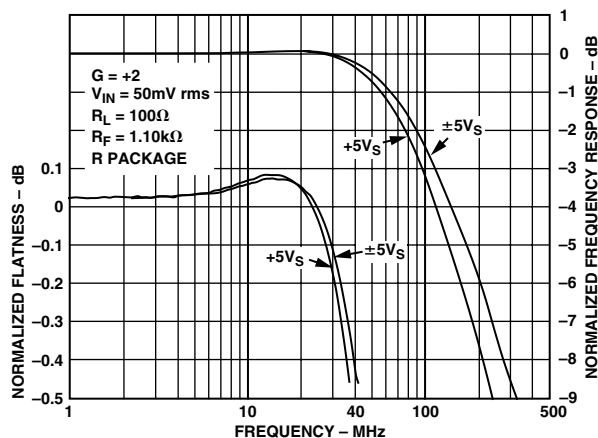


Figure 1. Frequency Response and Flatness, $G = +2$

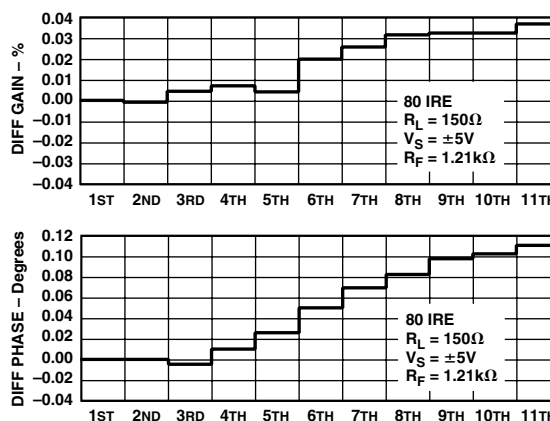


Figure 2. Differential Gain/Differential Phase

REV. D

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AD8004* PRODUCT PAGE QUICK LINKS

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COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- AD8004 Evaluation Board

DOCUMENTATION

Application Notes

- AN-356: User's Guide to Applying and Measuring Operational Amplifier Specifications
- AN-649: Using the Analog Devices Active Filter Design Tool
- AN-692: Universal Precision Op Amp Evaluation Board

Data Sheet

- AD8004: Quad 3000 V/ μ s, 35 mW Current Feedback Amplifier Data Sheet

User Guides

- UG-111: Universal Evaluation Board for Quad, High Speed Op Amps Offered in 14-Lead SOIC Packages

TOOLS AND SIMULATIONS

- AD8004 SPICE Macro-Model

REFERENCE MATERIALS

Product Selection Guide

- High Speed Amplifiers Selection Table

Tutorials

- MT-034: Current Feedback (CFB) Op Amps
- MT-051: Current Feedback Op Amp Noise Considerations
- MT-057: High Speed Current Feedback Op Amps
- MT-059: Compensating for the Effects of Input Capacitance on VFB and CFB Op Amps Used in Current-to-Voltage Converters

DESIGN RESOURCES

- AD8004 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all AD8004 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

AD8004—SPECIFICATIONS (@ $T_A = +25^\circ\text{C}$, $V_S = \pm 5\text{ V}$, $R_L = 100\ \Omega$, unless otherwise noted.)

| Parameter | Test Conditions/Comments | AD8004A | | | AD8004S | | | Unit |
|----------------------------------|---|---------|------|------|---------|------|------|--------|
| | | Min | Typ | Max | Min | Typ | Max | |
| DYNAMIC PERFORMANCE | | | | | | | | |
| Bandwidth for 0.1 dB Flatness | G = +2 | | 30 | | | 30 | | MHz |
| Slew Rate | G = +2, V _O = 4 V Step | | 3000 | | | 3000 | | V/μs |
| | G = −2, V _O = 4 V Step | | 2000 | | | 2000 | | V/μs |
| Settling Time to 0.1% | G = +2, V _O = 2 V Step | | 21 | | | 21 | | ns |
| Rise and Fall Time (10% to 90%) | G = +2, V _O = 2 V Step | | 1.8 | | | 1.8 | | ns |
| NOISE/HARMONIC PERFORMANCE | | | | | | | | |
| Total Harmonic Distortion | f _C = 5 MHz, V _O = 2 V p-p, R _L = 1 kΩ | | −78 | | | −78 | | dBc |
| Crosstalk, R Package, Worst Case | f = 5 MHz, G = +2, R _L = 1 kΩ | | −69 | | | | | dB |
| Input Voltage Noise | f = 10 kHz | | 1.5 | | | 1.5 | | nV/√Hz |
| Input Current Noise | f = 10 kHz, +In | | 38 | | | 38 | | pA/√Hz |
| | −In | | 38 | | | 38 | | pA/√Hz |
| Differential Gain Error | NTSC, G = +2, R _L = 150 Ω, R _F = 1.21 kΩ | | 0.04 | | | 0.04 | | % |
| Differential Phase Error | NTSC, G = +2, R _L = 150 Ω, R _F = 1.21 kΩ | | 0.10 | | | 0.10 | | Degree |
| Differential Gain Error | NTSC, G = +2, R _L = 1 kΩ, R _F = 1.21 kΩ | | 0.01 | | | 0.01 | | % |
| Differential Phase Error | NTSC, G = +2, R _L = 1 kΩ, R _F = 1.21 kΩ | | 0.04 | | | 0.04 | | Degree |
| DC PERFORMANCE | | | | | | | | |
| Input Offset Voltage | T _{MIN} to T _{MAX} | | 1.0 | 3.5 | | 1.0 | 3.5 | mV |
| | | | 1.5 | 5 | | 1.5 | 6 | mV |
| Offset Drift | | | 15 | | | 15 | | μV/°C |
| −Input Bias Current | T _{MIN} to T _{MAX} | | ±35 | ±90 | | ±35 | ±90 | μA |
| | | | | ±110 | | | ±120 | μA |
| +Input Bias Current | T _{MIN} to T _{MAX} | | ±40 | ±110 | | ±40 | ±110 | μA |
| | | | | ±120 | | | ±130 | μA |
| Open-Loop Transresistance | V _O = ±2.5 V T _{MIN} to T _{MAX} | 170 | 290 | | 170 | 290 | | kΩ |
| | | | 220 | | | 220 | | kΩ |
| INPUT CHARACTERISTICS | | | | | | | | |
| Input Resistance | +Input | | 2 | | | 2 | | MΩ |
| | −Input | | 50 | | | 50 | | Ω |
| Input Capacitance | +Input | | 1.5 | | | 1.5 | | pF |
| Input Common-Mode Voltage Range | | | 3.2 | | | 3.2 | | ±V |
| Common-Mode Rejection Ratio | | | | | | | | |
| Offset Voltage | V _{CM} = ±2.5 V | 52 | 58 | | 52 | 58 | | dB |
| −Input Current | V _{CM} = ±2.5 V, T _{MIN} to T _{MAX} | | 1 | | | 1 | | μA/V |
| +Input Current | V _{CM} = ±2.5 V, T _{MIN} to T _{MAX} | | 12 | | | 12 | | μA/V |
| OUTPUT CHARACTERISTICS | | | | | | | | |
| Output Voltage Swing | R _L = 150 Ω | | 3.9 | | | 3.9 | | ±V |
| Output Current | | | 50 | | | 50 | | mA |
| Short Circuit Current | | 100 | 180 | | 100 | 180 | | mA |
| POWER SUPPLY | | | | | | | | |
| Operating Range | | ±2.0 | | ±6.0 | ±2.0 | | ±6.0 | V |
| Total Quiescent Current | T _{MIN} to T _{MAX} | | 14 | 17 | | 14 | 17 | mA |
| | | | 16 | 20 | | 16 | 23 | mA |
| Power Supply Rejection Ratio | ΔV _S = ±2 V | 56 | 62 | | 56 | 62 | | dB |
| −Input Current | T _{MIN} to T _{MAX} | | 0.5 | | | 0.5 | | μA/V |
| +Input Current | T _{MIN} to T _{MAX} | | 4 | | | 4 | | μA/V |

Specifications subject to change without notice.

SPECIFICATIONS (@ $T_A = +25^\circ\text{C}$, $V_S = +5\text{ V}$, $R_L = 100\ \Omega$, unless otherwise noted.)

AD8004

| Parameter | Test Conditions/Comments | AD8004A | | | AD8004S | | | Unit |
|----------------------------------|---|---------|------------|------|---------|------------|------|--------|
| | | Min | Typ | Max | Min | Typ | Max | |
| DYNAMIC PERFORMANCE | | | | | | | | |
| Bandwidth for 0.1 dB Flatness | G = +2 | | 30 | | | 30 | | MHz |
| Slew Rate | G = +2, V _O = 2 V Step | | 1100 | | | 1100 | | V/μs |
| Settling Time to 0.1% | G = +2, V _O = 2 V Step | | 24 | | | 24 | | ns |
| Rise and Fall Time (10% to 90%) | G = +2, V _O = 2 V Step | | 2.3 | | | 2.3 | | ns |
| NOISE/HARMONIC PERFORMANCE | | | | | | | | |
| Total Harmonic Distortion | f _C = 5 MHz, V _O = 2 V p-p, R _L = 1 kΩ | | −65 | | | −65 | | dBc |
| Crosstalk, R Package, Worst Case | f = 5 MHz, G = +2, R _L = 1 kΩ | | −69 | | | | | dB |
| Input Voltage Noise | f = 10 kHz | | 1.5 | | | 1.5 | | nV/√Hz |
| Input Current Noise | f = 10 kHz, +In | | 38 | | | 38 | | pA/√Hz |
| | −In | | 38 | | | 38 | | pA/√Hz |
| Differential Gain Error | NTSC, G = +2, R _L = 150 Ω, R _F = 1.21 kΩ | | 0.06 | | | 0.06 | | % |
| Differential Phase Error | NTSC, G = +2, R _L = 150 Ω, R _F = 1.21 kΩ | | 0.25 | | | 0.25 | | Degree |
| Differential Gain Error | NTSC, G = +2, R _L = 1 kΩ, R _F = 1.21 kΩ | | 0.01 | | | 0.01 | | % |
| Differential Phase Error | NTSC, G = +2, R _L = 1 kΩ, R _F = 1.21 kΩ | | 0.08 | | | 0.08 | | Degree |
| DC PERFORMANCE | | | | | | | | |
| Input Offset Voltage | T _{MIN} to T _{MAX} | | 1.0 | 2.5 | | 1.0 | 2.5 | mV |
| | | | 1 | 3 | | 1 | 4 | mV |
| Offset Drift | T _{MIN} to T _{MAX} | | 15 | | | 15 | | μV/°C |
| −Input Bias Current | | | ±20 | ±80 | | ±20 | ±80 | μA |
| | | | | ±100 | | | ±110 | μA |
| +Input Bias Current | | | ±35 | ±100 | | ±35 | ±100 | μA |
| | T _{MIN} to T _{MAX} | | | ±115 | | | ±125 | μA |
| Open Loop Transresistance | V _O = +1.5 V to +3.5 V | 140 | 230 | | 140 | 230 | | kΩ |
| | T _{MIN} to T _{MAX} | | 170 | | | 170 | | kΩ |
| INPUT CHARACTERISTICS | | | | | | | | |
| Input Resistance | +Input | | 2 | | | 2 | | MΩ |
| | −Input | | 50 | | | 50 | | Ω |
| Input Capacitance | +Input | | 1.5 | | | 1.5 | | pF |
| Input Common-Mode Voltage Range | | | 3.2 | | | 3.2 | | V |
| Common-Mode Rejection Ratio | | | | | | | | |
| Offset Voltage | V _{CM} = +1 V to +3 V | 52 | 57 | | 52 | 57 | | dB |
| −Input Current | V _{CM} = +1 V to +3 V, T _{MIN} to T _{MAX} | | 2 | | | 2 | | μA/V |
| +Input Current | V _{CM} = +1 V to +3 V, T _{MIN} to T _{MAX} | | 15 | | | 15 | | μA/V |
| OUTPUT CHARACTERISTICS | | | | | | | | |
| Output Voltage Swing | R _L = 150 Ω | | 0.9 to 4.1 | | | 0.9 to 4.1 | | V |
| Output Current | | | 50 | | | 50 | | mA |
| Short Circuit Current | | | 95 | | | 95 | | mA |
| POWER SUPPLY | | | | | | | | |
| Operating Range | | 0, +4 | | +12 | 0, +4 | | +12 | V |
| Total Quiescent Current | | | 13 | 14 | | 13 | 14 | mA |
| | T _{MIN} to T _{MAX} | | 14.5 | 15.5 | | 14.5 | 17.5 | mA |
| Power Supply Rejection Ratio | ΔV _S = +1 V, V _{CM} = +2.5 V | 56 | 62 | | 56 | 62 | | dB |
| −Input Current | T _{MIN} to T _{MAX} | | 1 | | | 1 | | μA/V |
| +Input Current | T _{MIN} to T _{MAX} | | 6 | | | 6 | | μA/V |

Specifications subject to change without notice.

AD8004

ABSOLUTE MAXIMUM RATINGS^{1,2}

| | |
|---|-------------------------------|
| Supply Voltage | 12.6 V |
| Internal Power Dissipation | Note 2 |
| Input Voltage (Common Mode) | $\pm V_S$ |
| Differential Input Voltage | ± 2.5 V |
| Output Short Circuit Duration | Observe Power Derating Curves |
| Storage Temperature Range (R) | -65°C to +125°C |
| Operating Temperature Range | |
| A Grade | -40°C to +85°C |
| S Grade | -55°C to +125°C |
| Lead Temperature Range (Soldering 10 sec) | +300°C |

NOTES

¹Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²Specification is for device in free air:

14-Lead SOIC Package: $\theta_{JA} = 140^{\circ}\text{C/W}$, $\theta_{JC} = 30^{\circ}\text{C/W}$

MAXIMUM POWER DISSIPATION

The maximum power that can be safely dissipated by the AD8004 is limited by the associated rise in junction temperature. The maximum safe junction temperature for plastic encapsulated devices is determined by the glass transition temperature of the plastic, approximately +150°C. Exceeding this limit temporarily may cause a shift in parametric performance due to a change in the stresses exerted on the die by the package. Exceeding a junction temperature of +175°C for an extended period can result in device failure.

While the AD8004 is internally short circuit protected, this may not be sufficient to guarantee that the maximum junction temperature is not exceeded under all conditions. To ensure proper operation, it is necessary to observe the maximum power ratings.

ORDERING GUIDE

| Model ¹ | Temperature Range | Package Description | Package Option |
|--------------------|-------------------|---------------------|----------------|
| AD8004ARZ-14 | -40°C to +85°C | 14-Lead SOIC | R-14 |
| AD8004ARZ-14-REEL7 | -40°C to +85°C | 7" Tape and Reel | R-14 |
| AD8004AR-EBZ | | Evaluation Board | |

¹ Z = RoHS Compliant Part.

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD8004 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

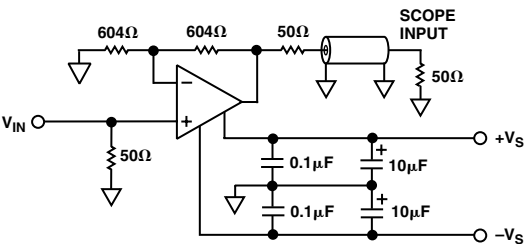


Figure 3. Test Circuit; Gain = -2

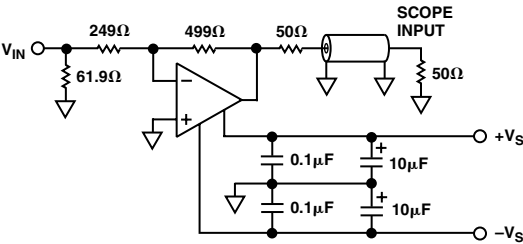
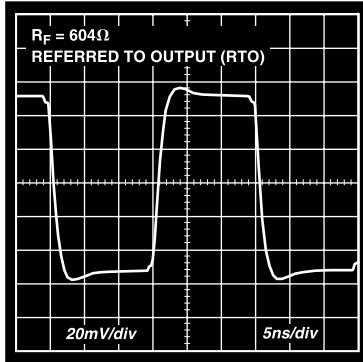
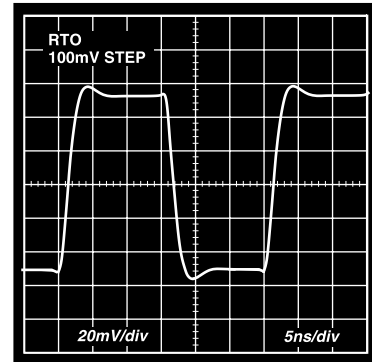


Figure 4. Test Circuit; Gain = -2

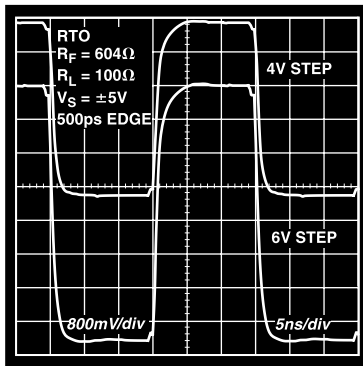
Typical Performance Characteristics—AD8004



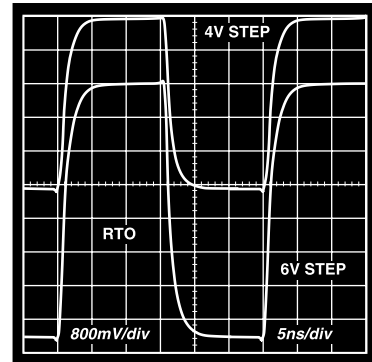
TPC 1.¹ 100 mV Step Response; $G = +2$, $V_S = \pm 2.5 \text{ V}$ or $\pm 5 \text{ V}$



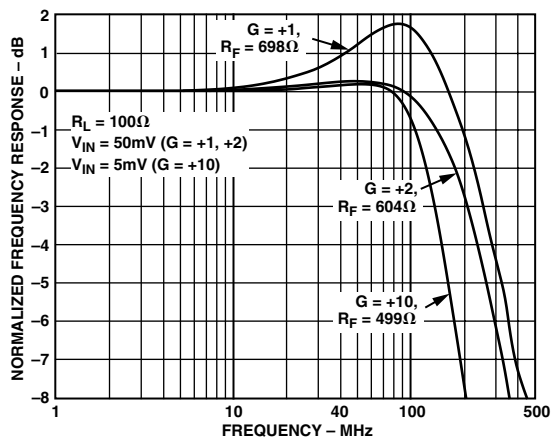
TPC 4.¹ 100 mV Step Response; $G = -2$, $V_S = \pm 2.5 \text{ V}$ or $\pm 5 \text{ V}$



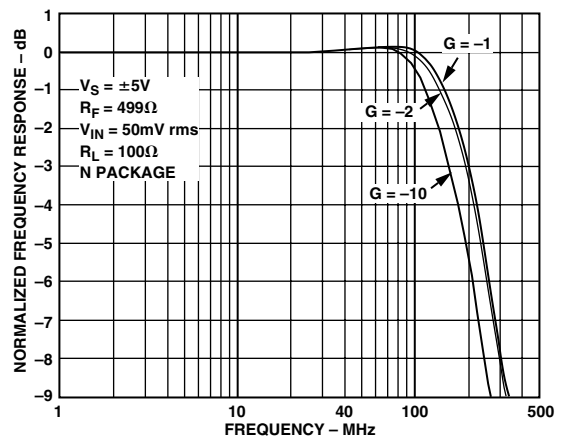
TPC 2.¹ Step Response; $G = +2$, $V_S = \pm 5 \text{ V}$



TPC 5.¹ Step Response; $G = -2$, $V_S = \pm 5 \text{ V}$



TPC 3. Frequency Response; $G = +1, +2, +10$; $V_S = \pm 5 \text{ V}$

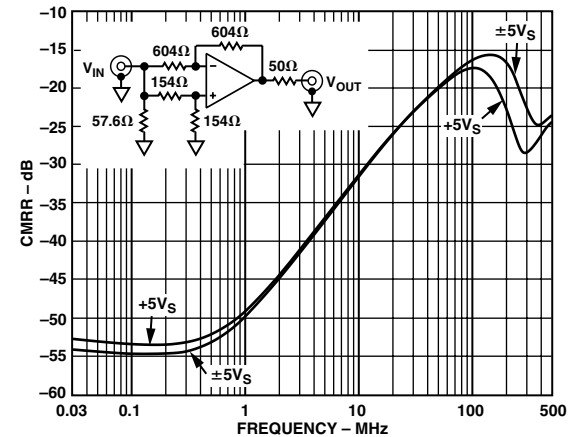
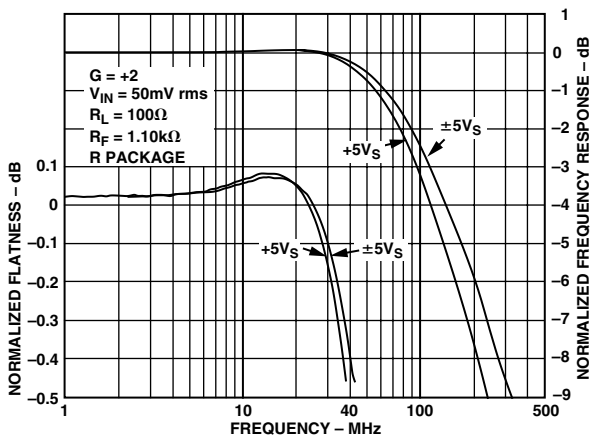
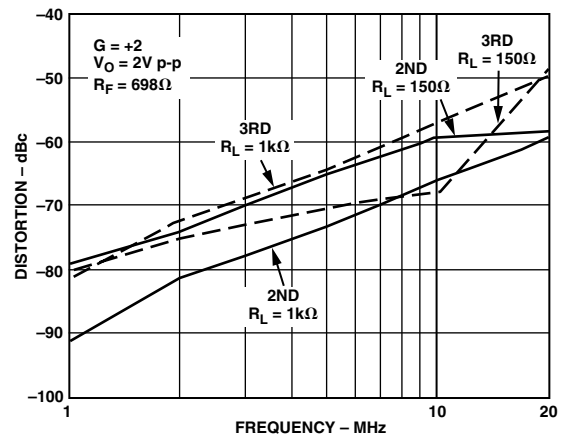
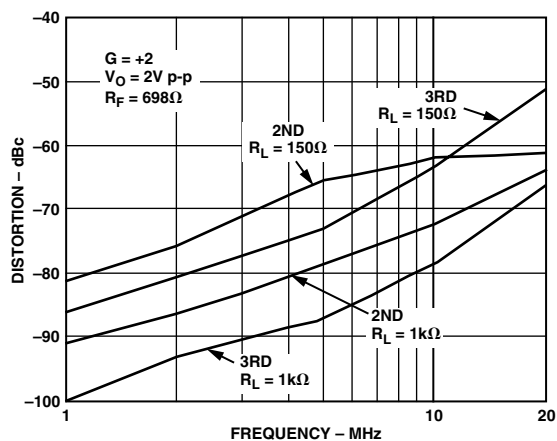
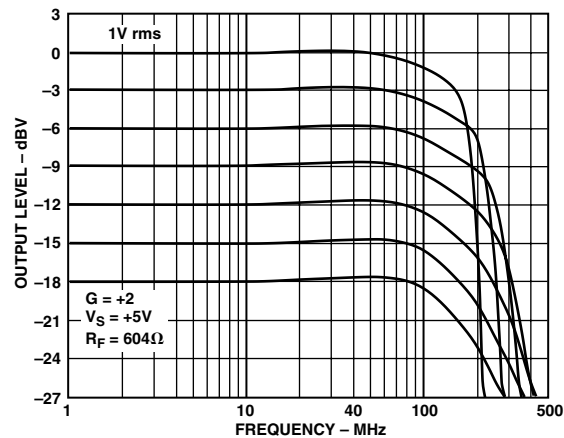
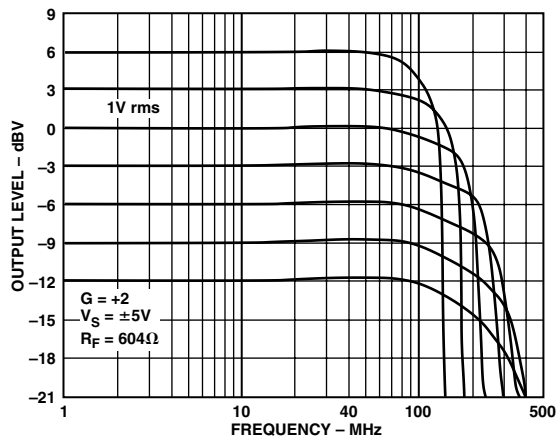


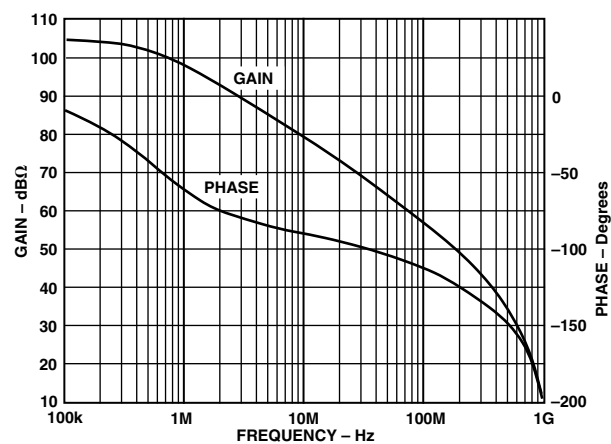
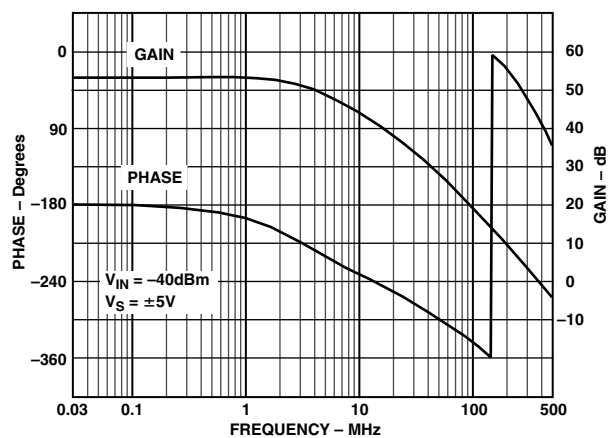
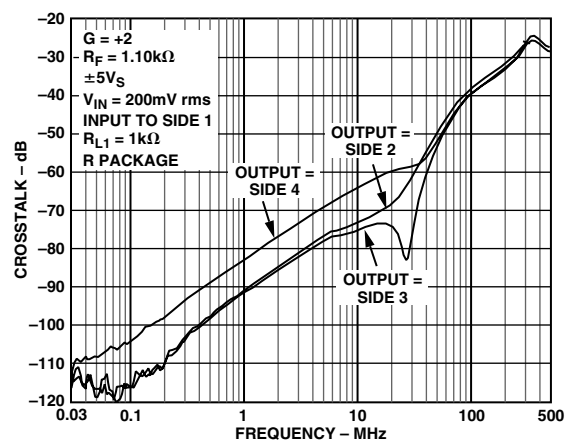
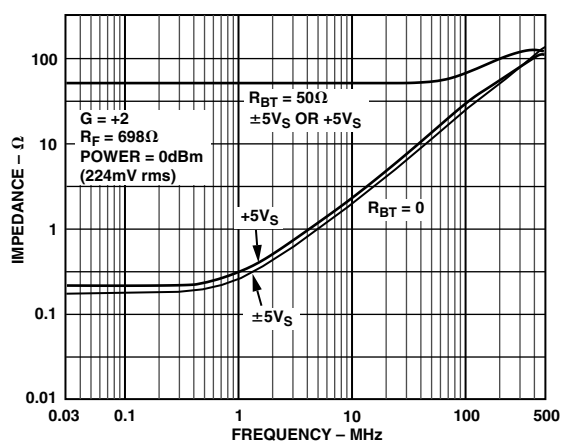
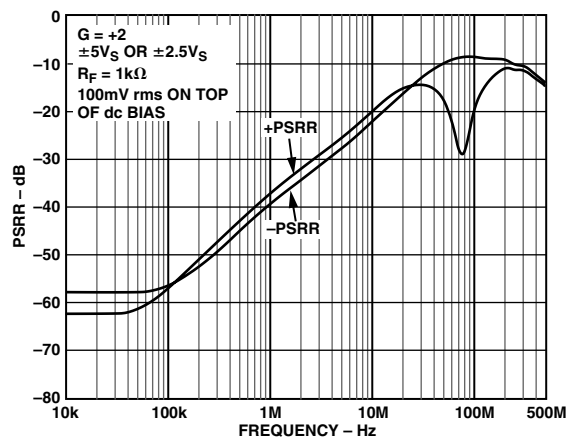
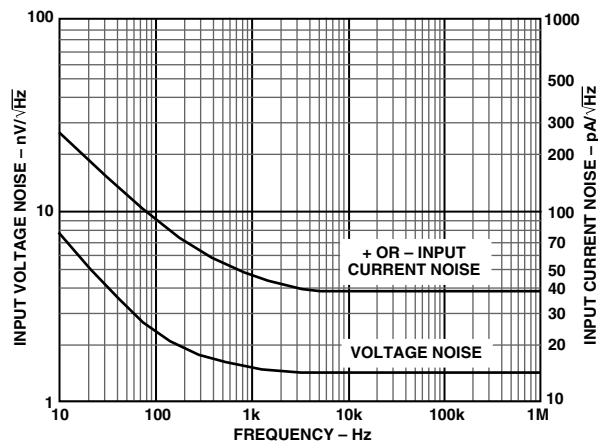
TPC 6.² Frequency Response; $G = -1, -2, -10$

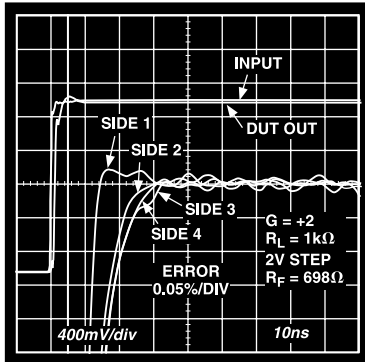
¹ $V_S = \pm 2.5 \text{ V}$ operation is identical to $V_S = +5 \text{ V}$ single-supply operation.

² The N-14 package option is no longer available; the R-14 package performance may vary.

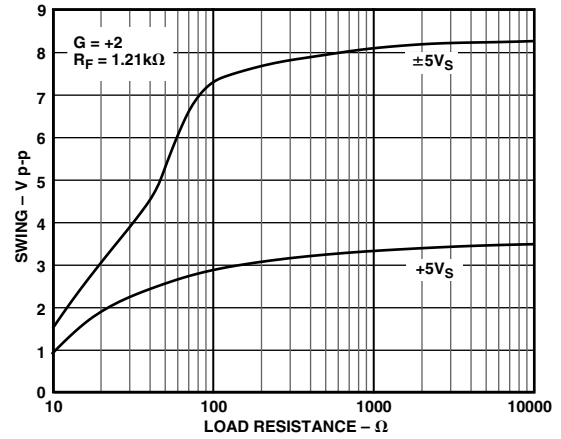
AD8004



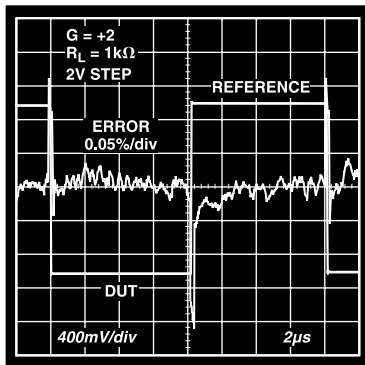




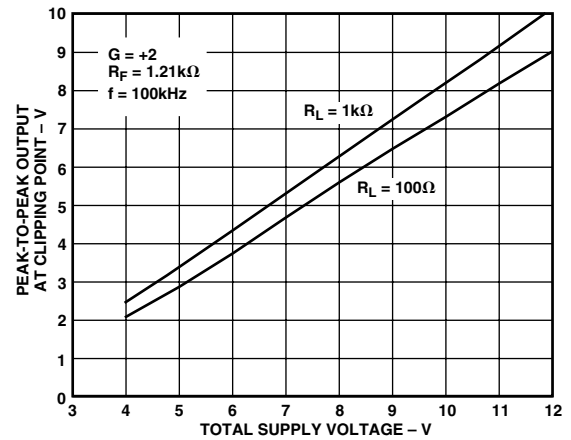
TPC 19. Short-Term Settling Time



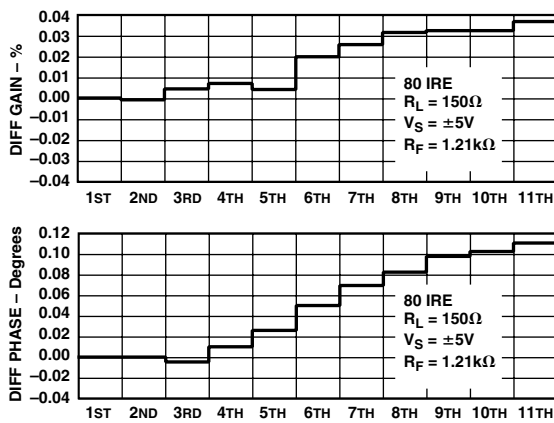
TPC 22. Output Voltage Swing vs. Load



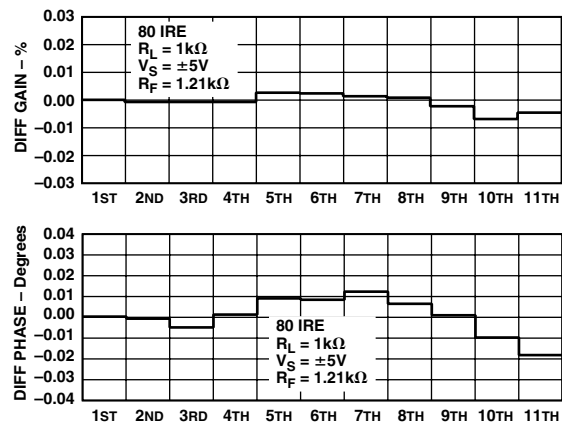
TPC 20. Long-Term Settling Time



TPC 23. Output Swing vs. Supply



TPC 21. Differential Gain/Differential Phase



TPC 24. Differential Gain/Phase, $R_L = 1\text{ k}\Omega$

THEORY OF OPERATION

The AD8004 is a member of a new family of high speed current-feedback (CF) amplifiers offering new levels of bandwidth, distortion, and signal-swing capability vs. power. Its wide dynamic range capabilities are due to both a complementary high speed bipolar process and a new design architecture. The AD8004 is basically a two stage (Figure 30) rather than the conventional one stage design. Both stages feature the current-on-demand property associated with current feedback amplifiers. This gives an unprecedented ratio of quiescent current to dynamic performance. The important properties of slew rate and full power bandwidth benefit from this performance. In addition the second gain stage buffers the effects of load impedance, significantly reducing distortion.

A full discussion of this new amplifier architecture is available on the data sheet for the AD8011. This discussion only covers the basic principles of operation.

DC AND AC CHARACTERISTICS

As with traditional op amp circuits the dc closed-loop gain is defined as:

$$A_V = G = 1 + \frac{R_F}{R_N} \quad \text{noninverting operation}$$

$$A_V = G = -\frac{R_F}{R_N} \quad \text{inverting operation}$$

The more exact relationships that take into account open-loop gain errors are:

$$A_V = \frac{G}{1 + \frac{1-G}{A_O(s)} + \frac{R_F}{T_O(s)}} \quad \text{for inverting (G is negative)}$$

$$A_V = \frac{G}{1 + \frac{G}{A_O(s)} + \frac{R_F}{T_O(s)}} \quad \text{for noninverting (G is positive)}$$

In these equations the open-loop voltage gain ($A_O(s)$) is common to both voltage and current-feedback amplifiers and is the ratio of output voltage to differential input voltage. The open-loop transimpedance gain ($T_O(s)$) is the ratio of output voltage to inverting input current and is applicable to current-feedback amplifiers. The open-loop voltage gain and open-loop transimpedance gain ($T_O(s)$) of the AD8004 are plotted vs. frequency in TPCs 15 and 18. These plots and the basic relationships can be used to predict the first order performance of the AD8004 over frequency. At low closed-loop gains the term ($R_F/T_O(s)$) dominates the frequency response characteristics. This gives the result that bandwidth is constant with gain, a familiar property of current feedback amplifiers.

An R_F of 1 k Ω has been chosen as the nominal value to give optimum frequency response with acceptable peaking at gains of +2/-1. As can be seen from the above relationships, at higher closed-loop gains reducing R_F has the effect of increasing closed-loop bandwidth. Table I gives optimum values for R_F and R_G for a variety of gains.

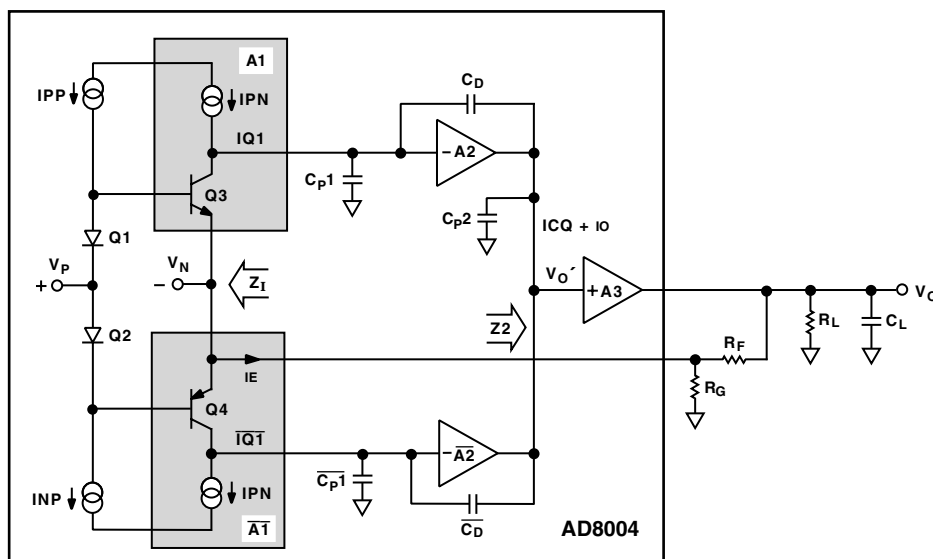


Figure 5. Simplified Block Diagram

AD8004

DRIVING CAPACITIVE LOADS

The AD8004 was designed primarily to drive nonreactive loads. If driving loads with a capacitive component is desired, best settling response is obtained by the addition of a small series resistance as shown in Figure 6. The accompanying graph shows the optimum value for R_{SERIES} vs. capacitive load. It is worth noting that the frequency response of the circuit when driving large capacitive loads will be dominated by the passive roll-off of R_{SERIES} and C_L .

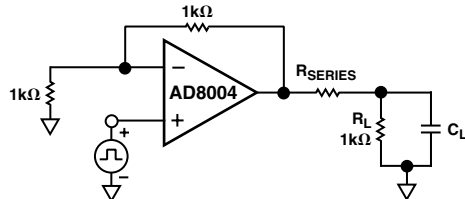


Figure 6. Driving Capacitive Load

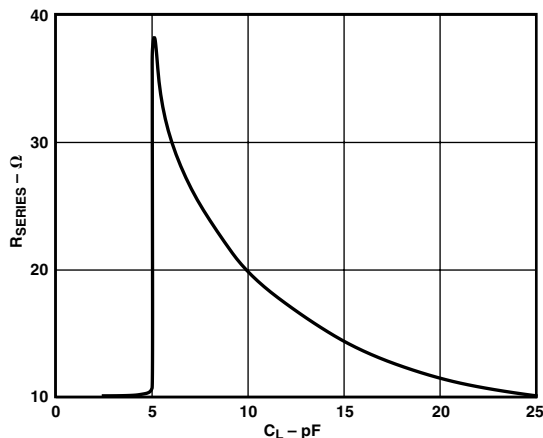


Figure 7. Recommended R_{SERIES} vs. Capacitive Load for ≤ 30 ns Settling to 0.1%

OPTIMIZING FLATNESS

The fine scale gain flatness and -3 dB bandwidth is affected by R_{FEEDBACK} selection as is normal of current feedback amplifiers. With the exception of gain = +1, the AD8004 can be adjusted for either maximal flatness with modest closed-loop bandwidth or for mildly peaked-up frequency response with much more bandwidth. Figure 8 shows the effect of three evenly spaced R_F changes upon gain = +1 and gain = +2. Table I shows the recommended component values for achieving maximally flat frequency response as well as a faster slightly peaked-up frequency response.

Printed circuit board parasitics and device lead frame parasitics also control fine scale gain flatness. In the printed circuit board environment, parasitics such as extra capacitance caused by two parallel and vertical flat conductors on opposite PC board sides in the region of the summing junction will cause some bandwidth extension and/or increased peaking.

In noninverting gains, the effect of extra capacitance on summing junctions is far more pronounced than with inverting gains. Figure 9 shows an example of this. Note that only 1 pF of added junction capacitance causes about a 70% bandwidth extension and additional peaking on a gain = +2. For an inverting gain = -2 , 5 pF of additional summing junction capacitance caused a small 10% bandwidth extension.

Extra output capacitive loading also causes bandwidth extensions and peaking. The effect is more pronounced with less resistive loading from the next stage. Figure 10 shows the effect of direct output capacitive loads for gains of +2 and -2 . For both gains C_{LOAD} was set to 10 pF or 0 pF (no extra capacitive loading). For each of the four traces in Figure 10 the resistive loads were 100 Ω . Figure 11 also shows capacitive loading effects with a lighter output resistive load. Note that even though bandwidth is extended 2 \times , the flatness dramatically suffers.

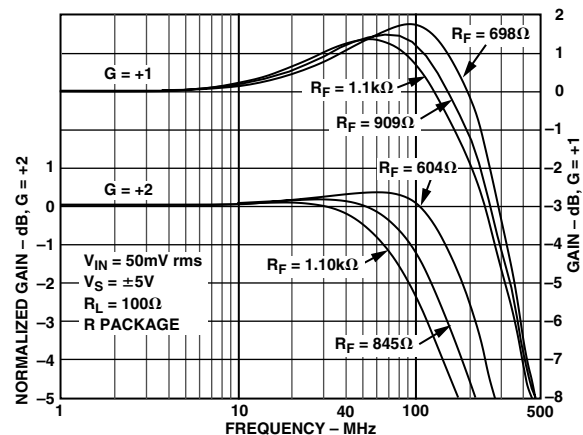


Figure 8. R_{FEEDBACK} vs. Frequency Response, $G = +1/+2$

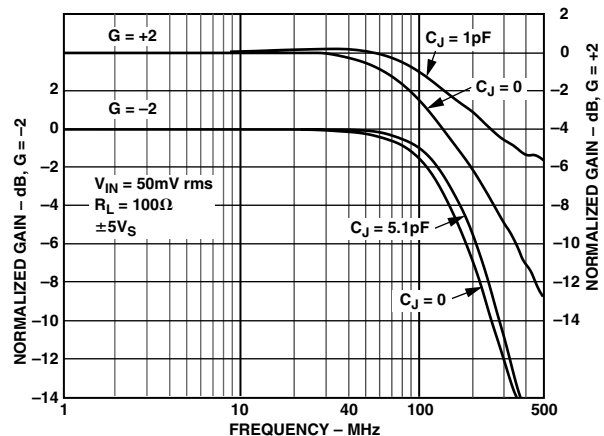


Figure 9. Frequency Response vs. Added Summing Junction Capacitance

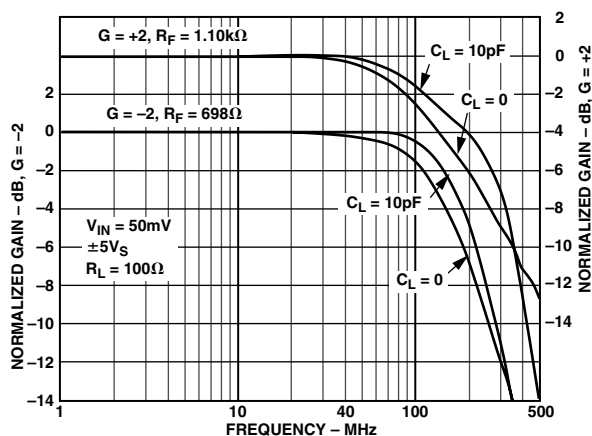


Figure 10. Frequency Response vs. Capacitive Loading, $R_L = 100\ \Omega$ Output

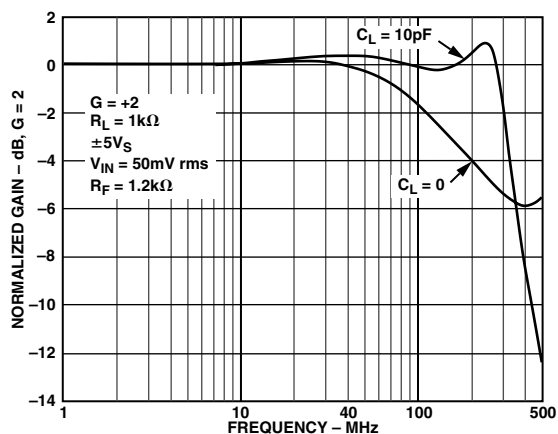


Figure 11. Flatness with 10 pF Capacitive Load

DRIVING A SINGLE-SUPPLY A/D CONVERTER

New CMOS A/D converters are placing greater demands on the amplifiers that drive them. Higher resolutions, faster conversion rates, and input switching irregularities require superior settling characteristics. In addition, these devices run off a single +5 V supply and consume little power, so good single-supply operation with low power consumption is very important. The AD8004 is well positioned for driving this new class of A/D converters.

Figure 12 shows a circuit that uses an AD8004 to drive an AD876, a single supply, 10-bit, 20 MSPS A/D converter that requires only 140 mW. Using the AD8004 for level shifting and driving, the A/D exhibits no degradation in performance compared to when it is driven from a signal generator.

The analog input of the AD876 spans 2 V centered at about 2.6 V. The resistor network and bias voltages provide the level shifting and gain required to convert the 0 V to 1 V input signal to a 3.6 V to 1.6 V range that the AD876 wants to see.

Biasing the noninverting input of the AD8004 at 1.6 V dc forces the inverting input to be at 1.6 V dc for linear operation of the amplifier. When the input is at 0 V, there is 3.2 mA flowing out of the summing junction via R1 (1.6 V/499 Ω). R3 has a current of 1.2 mA flowing into the summing junction (3.6 V – 1.6 V)/1.65 k Ω . The difference of these two currents (2 mA) must flow

through R2. This current flows toward the summing junction and requires that the output be 2 V higher than the summing junction or at 3.6 V.

When the input is at 1 V, there is 1.2 mA flowing into the summing junction through R3 and 1.2 mA flowing out through R1. These currents balance and leave no current to flow through R2. Thus the output is at the same potential as the inverting input or 1.6 V.

The input of the AD876 has a series MOSFET switch that turns on and off at the sampling rate. This MOSFET is connected to a hold capacitor internal to the device. The on impedance of the MOSFET is about 50 Ω , while the hold capacitor is about 5 pF.

In a worst case condition, the input voltage to the AD876 will change by a full-scale value (2 V) in one sampling cycle. When the input MOSFET turns on, the output of the op amp will be connected to the charged hold capacitor through the series resistance of the MOSFET. Without any other series resistance, the instantaneous current that flows would be 40 mA. This would cause settling problems for the op amp.

The series 100 Ω resistor limits the current that flows instantaneously after the MOSFET turns on to about 13 mA. This resistor cannot be made too large or the high frequency performance will be affected.

The sampling MOSFET of the AD876 is closed for only half of each cycle or for 25 ns. Approximately seven time constants are required for settling to 10 bits. The series 100 Ω resistor along with the 50 Ω on resistance and the hold capacitor, create a 750 ps time constant. These values leave a comfortable margin for settling. Obtaining the same results with the op amp A/D combination as compared to driving with a signal generator indicates that the op amp is settling fast enough.

Overall the AD8004 provides adequate buffering for the AD876 A/D converter without introducing distortion greater than that of the A/D converter by itself.

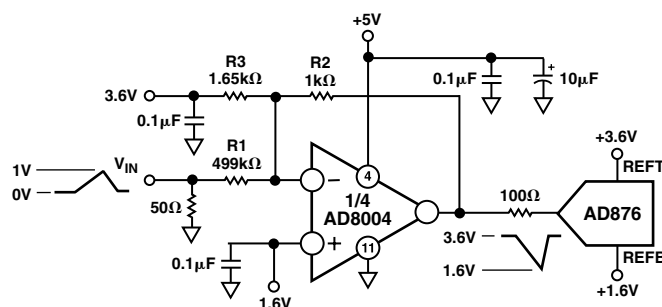


Figure 12. AD8004 Driving the AD876

LAYOUT CONSIDERATIONS

The specified high speed performance of the AD8004 requires careful attention to board layout and component selection. Table I shows the recommended component values for the AD8004 and Figures 14–16 show the layout for the AD8004 evaluation board (14-lead SOIC). Proper R_F design techniques and low parasitic component selection are mandatory.

AD8004

The PCB should have a ground plane covering all unused portions of the component side of the board to provide a low impedance ground path. The ground plane should be removed from the area near the input pins to reduce stray capacitance.

Chip capacitors should be used for supply bypassing (see Figure 13). One end should be connected to the ground plane and the other within 1/8" of each power pin. An additional (4.7 μ F to 10 μ F) tantalum electrolytic capacitor should be connected in parallel.

The feedback resistor should be located close to the inverting input pin in order to keep the stray capacitance at this node to a minimum. Capacitance greater than 1 pF at the inverting input will significantly affect high speed performance when operating at low noninverting gains. An example of extra inverting input capacitance can be seen on the plot of Figure 10.

Stripline design techniques should be used for long signal traces (greater than about 1"). These should be designed with the proper system characteristic impedance and be properly terminated at each end.

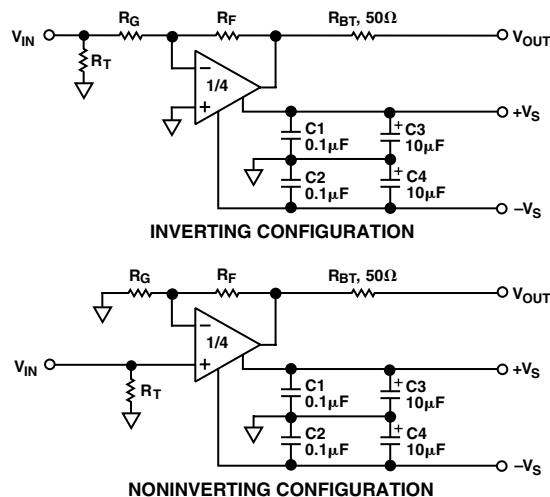


Figure 13. Inverting and Noninverting Configurations

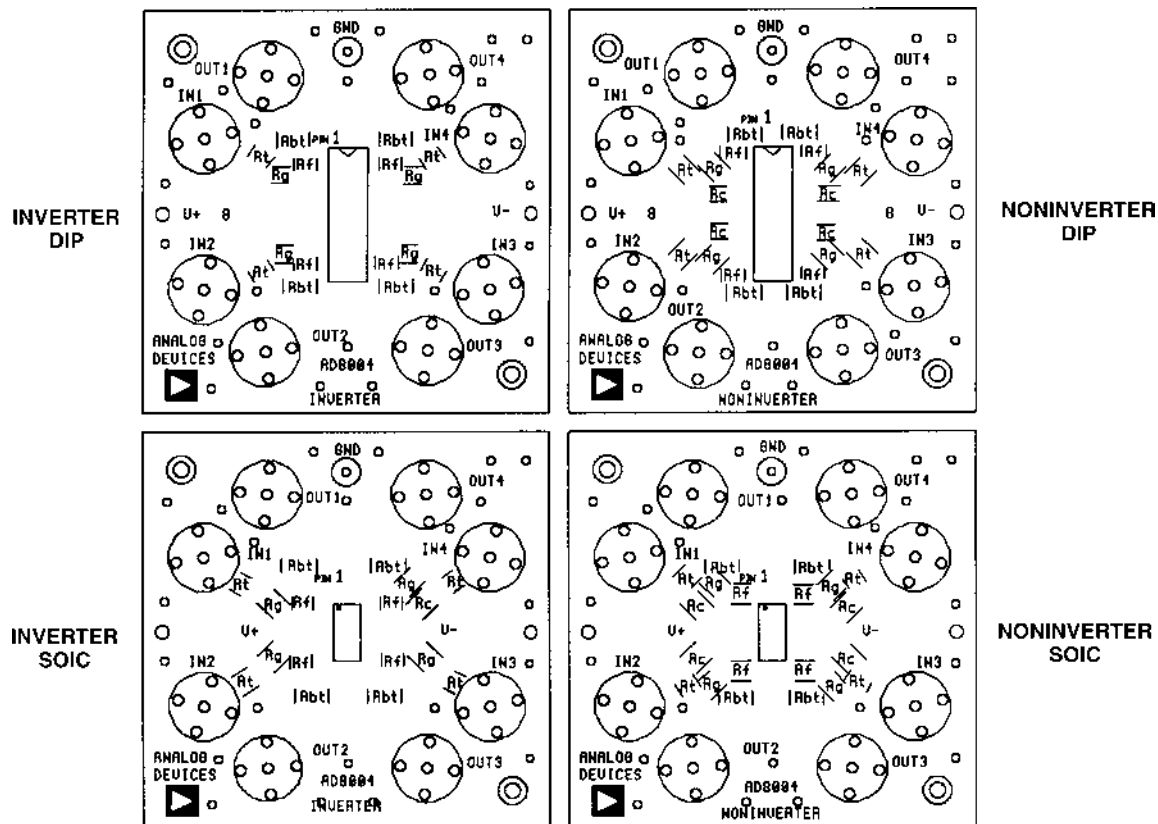
Table I. Recommended Component Values¹ and Typical Bandwidths

| Gain | -10 | -2 | Alternate -2 | -1 | Alternate -1 | +1 | Alternate +1 | +2 | Alternate +2 | +10 |
|--|----------|----------|-----------------|------|-----------------|--------|-----------------|----------|-----------------|----------|
| AD8004 (SOIC) PACKAGE TYPE | | | | | | | | | | |
| R_F (Ω) | 499 | 698 | 499 | 750 | 499 | 1.10 k | 698 | 1.10 k | 604 | 499 |
| R_G (Ω) | 49.9 | 348 | 249 | 750 | 499 | | | 1.10 k | 604 | 54.9 |
| R_T^2 (Ω) | None | 57.6 | 61.9 | 53.6 | 54.9 | 50 | 50 | 50 | 50 | 50 |
| Small Signal BW @ $\pm 5 V_S$ (MHz) | 155 | 130 | 190 | 125 | 195 | 150 | 225 | 110 | 175 | 135 |
| Peaking @ $\pm 5 V_S$ | < 0.7 dB | < 0.1 dB | 0.5 dB | None | 0.4 dB | 1.3 dB | 1.8 dB | < 0.1 dB | 0.5 dB | < 0.2 dB |
| 0.1 dB Flatness @ $\pm 5 V_S$ (MHz) | | 35 | | 25 | | | | 30 | | |
| Small Signal BW @ +5 V_S (MHz) | 135 | 115 | 175 | 110 | 165 | 130 | 195 | 95 | 155 | 120 |

NOTES

¹Resistor values listed are standard 1% tolerance.

² R_T chosen for 50 Ω characteristic input impedance.



NOTES:

1. R_T (INPUT TERMINATION RESISTOR) IS MOUNTED ON BOARD BOTTOMS.
2. R_C (IN SERIES WITH INPUT) IS A SHORT ON AD8004.
3. BYPASS CHIP CAPACITORS ARE MOUNTED ON BOARD BOTTOM WITH $0.1\mu F$ BEING CLOSEST TO SUPPLY PINS.
4. ON BOTH INVERTER BOARDS R_G , R_F AND R_{BT} ARE MOUNTED ON BOARD TOP.
5. ON NONINVERTER DIP BOARDS, R_F AND R_{BT} ARE ON BOARD TOP WHILE R_G IS ON BOTTOM. ON NONINVERTER SOIC BOARD, R_{BT} IS ON TOP WHILE R_F AND R_G ARE ON BOARD BOTTOM.

Figure 14.1 Evaluation Board Silkscreen (Top)

¹ The DIP package option is no longer available.

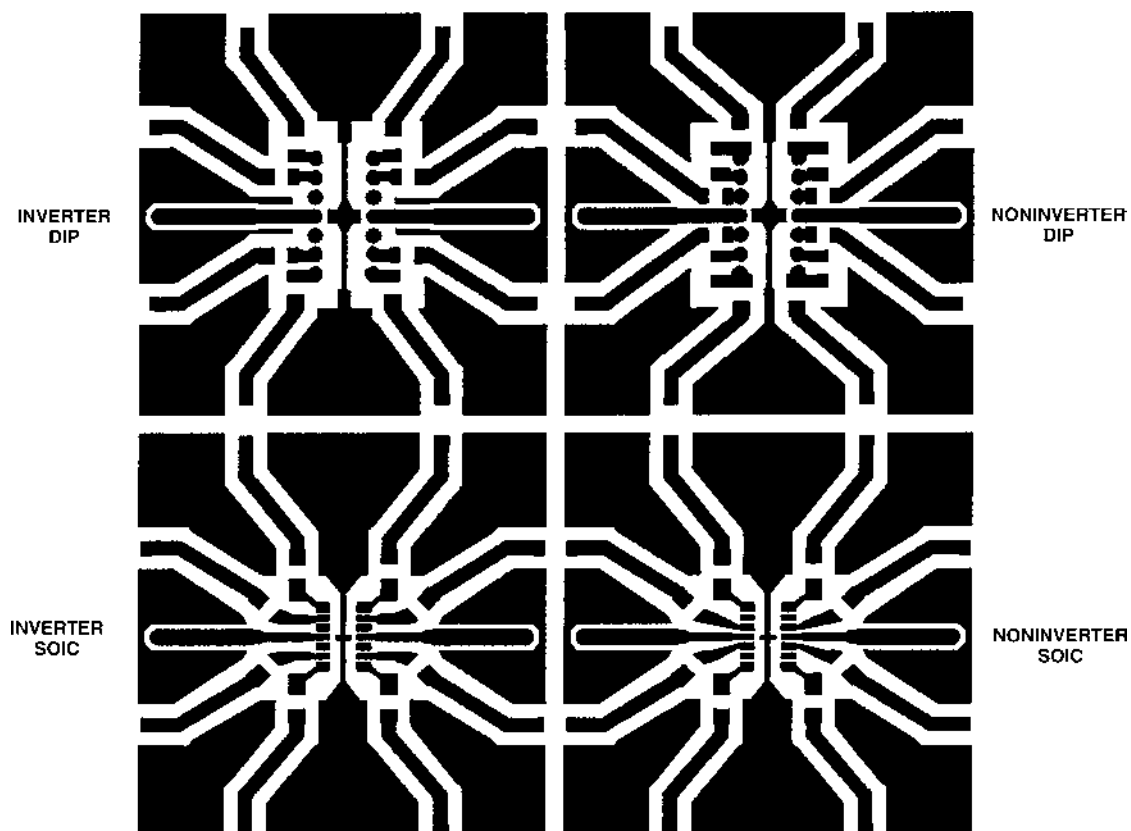


Figure 15 Evaluation Board Layout (Top Side)

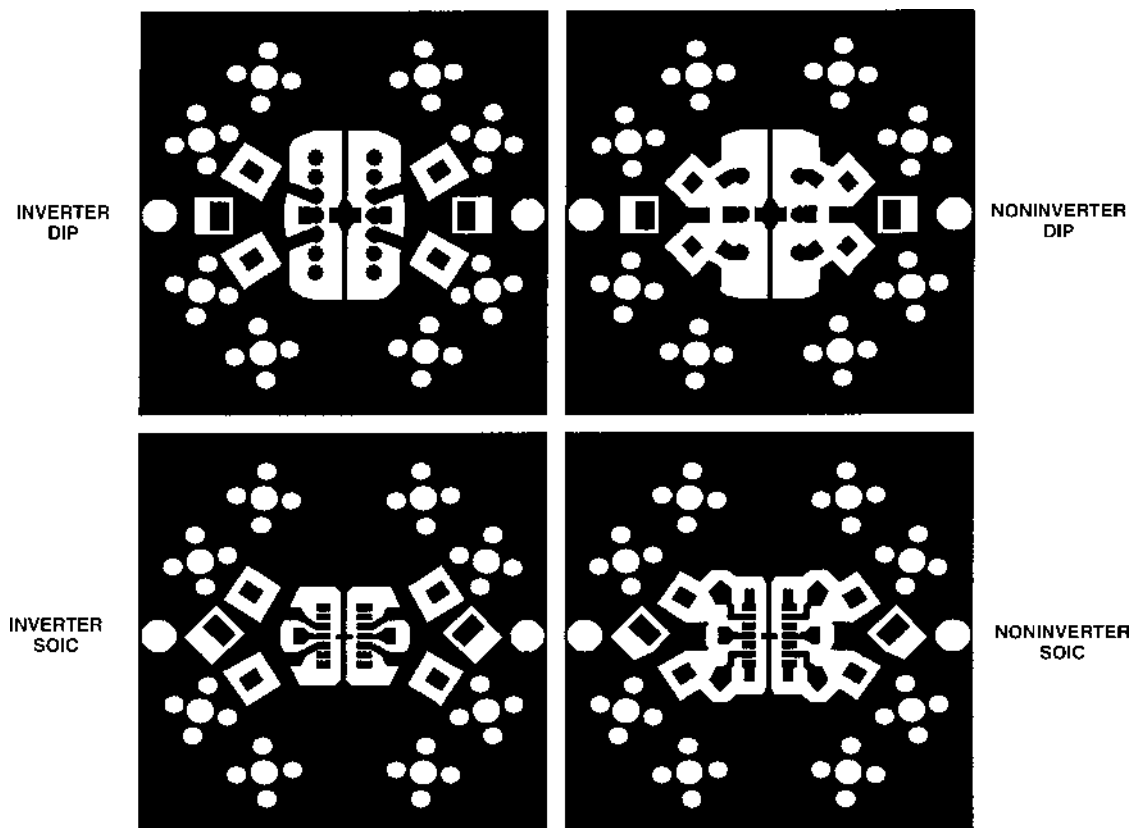


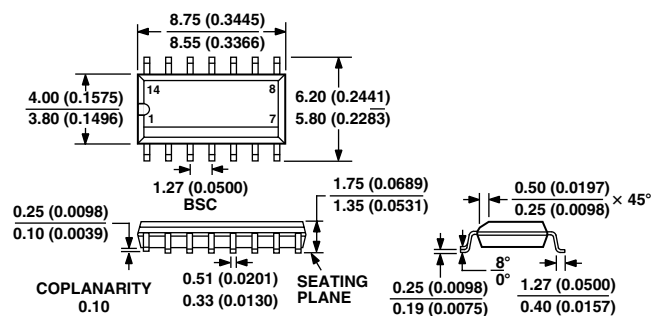
Figure 16.¹ Evaluation Board Layout (Bottom Side, Looking Through the Board)

¹ The DIP package option is no longer available.

OUTLINE DIMENSIONS

**14-Lead Standard Small Outline Package [SOIC]
(R-14)**

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

AD8004

Revision History

| Location | Page |
|--|-----------|
| 12/15—Data Sheet changed from REV. C to REV. D. | |
| Deleted 14-Lead PDIP and 14-Lead Cerdip Package | Universal |
| Changes to ORDERING GUIDE | 4 |
| 3/03—Data Sheet changed from REV. B to REV. C. | |
| Updated format | Universal |
| Added Cerdip (Q) Package | 1 |
| Added text to GENERAL DESCRIPTION | 1 |
| Changes to SPECIFICATIONS | 2 |
| Changes to ABSOLUTE MAXIMUM RATINGS | 4 |
| Changes to ORDERING GUIDE | 4 |
| Edited MAXIMUM POWER DISSIPATION section | 4 |
| Deleted Figure 3 | 4 |
| Edited Y axis of TPC 13 | 7 |
| Edited OPTIMIZING FLATNESS section | 10 |
| Edits to Figure 13 | 12 |
| Changes to Table I | 12 |
| Updated OUTLINE DIMENSIONS | 15 |

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